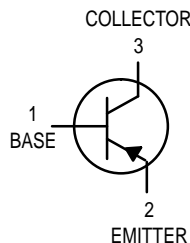


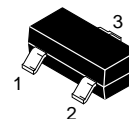
# General Purpose Transistor

## PNP Silicon



**MMBT3906LT1**

Motorola Preferred Device



CASE 318-08, STYLE 6  
SOT-23 (TO-236AB)

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	-40	Vdc
Collector-Base Voltage	$V_{CBO}$	-40	Vdc
Emitter-Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current — Continuous	$I_C$	-200	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board <sup>(1)</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, <sup>(2)</sup> $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### DEVICE MARKING

MMBT3906LT1 = 2A

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage <sup>(3)</sup> ( $I_C = -1.0 \text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	-40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = -10 \mu\text{Adc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	-40	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = -10 \mu\text{Adc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	-5.0	—	Vdc
Base Cutoff Current ( $V_{CE} = -30 \text{ Vdc}$ , $V_{EB} = -3.0 \text{ Vdc}$ )	$I_{BL}$	—	-50	nAdc
Collector Cutoff Current ( $V_{CE} = -30 \text{ Vdc}$ , $V_{EB} = -3.0 \text{ Vdc}$ )	$I_{CEX}$	—	-50	nAdc

- FR-5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$
- Alumina =  $0.4 \times 0.3 \times 0.024 \text{ in.}$  99.5% alumina.
- Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

Thermal Clad is a trademark of the Bergquist Company.

**Preferred** devices are Motorola recommended choices for future use and best overall value.

# MMBT3906LT1

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS(3)</b>				
DC Current Gain (I <sub>C</sub> = -0.1 mA <sub>dc</sub> , V <sub>CE</sub> = -1.0 V <sub>dc</sub> ) (I <sub>C</sub> = -1.0 mA <sub>dc</sub> , V <sub>CE</sub> = -1.0 V <sub>dc</sub> ) (I <sub>C</sub> = -10 mA <sub>dc</sub> , V <sub>CE</sub> = -1.0 V <sub>dc</sub> ) (I <sub>C</sub> = -50 mA <sub>dc</sub> , V <sub>CE</sub> = -1.0 V <sub>dc</sub> ) (I <sub>C</sub> = -100 mA <sub>dc</sub> , V <sub>CE</sub> = -1.0 V <sub>dc</sub> )	H <sub>FE</sub>	60 80 100 60 30	— — 300 — —	—
Collector-Emitter Saturation Voltage (I <sub>C</sub> = -10 mA <sub>dc</sub> , I <sub>B</sub> = -1.0 mA <sub>dc</sub> ) (I <sub>C</sub> = -50 mA <sub>dc</sub> , I <sub>B</sub> = -5.0 mA <sub>dc</sub> )	V <sub>CE(sat)</sub>	— —	-0.25 -0.4	V <sub>dc</sub>
Base-Emitter Saturation Voltage (I <sub>C</sub> = -10 mA <sub>dc</sub> , I <sub>B</sub> = -1.0 mA <sub>dc</sub> ) (I <sub>C</sub> = -50 mA <sub>dc</sub> , I <sub>B</sub> = -5.0 mA <sub>dc</sub> )	V <sub>BE(sat)</sub>	-0.65 —	-0.85 -0.95	V <sub>dc</sub>

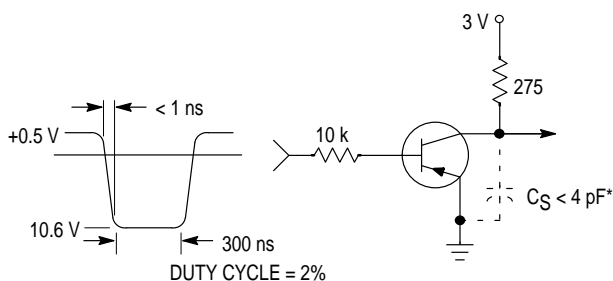
## SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product (I <sub>C</sub> = -10 mA <sub>dc</sub> , V <sub>CE</sub> = -20 V <sub>dc</sub> , f = 100 MHz)	f <sub>T</sub>	250	—	MHz
Output Capacitance (V <sub>CB</sub> = -5.0 V <sub>dc</sub> , I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	—	4.5	pF
Input Capacitance (V <sub>EB</sub> = -0.5 V <sub>dc</sub> , I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	—	10	pF
Input Impedance (I <sub>C</sub> = -1.0 mA <sub>dc</sub> , V <sub>CE</sub> = -10 V <sub>dc</sub> , f = 1.0 kHz)	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback Ratio (I <sub>C</sub> = -1.0 mA <sub>dc</sub> , V <sub>CE</sub> = -10 V <sub>dc</sub> , f = 1.0 kHz)	h <sub>re</sub>	0.1	10	X 10 <sup>-4</sup>
Small-Signal Current Gain (I <sub>C</sub> = -1.0 mA <sub>dc</sub> , V <sub>CE</sub> = -10 V <sub>dc</sub> , f = 1.0 kHz)	h <sub>fe</sub>	100	400	—
Output Admittance (I <sub>C</sub> = -1.0 mA <sub>dc</sub> , V <sub>CE</sub> = -10 V <sub>dc</sub> , f = 1.0 kHz)	h <sub>oe</sub>	3.0	60	μmhos
Noise Figure (I <sub>C</sub> = -100 μA <sub>dc</sub> , V <sub>CE</sub> = -5.0 V <sub>dc</sub> , R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz)	NF	—	4.0	dB

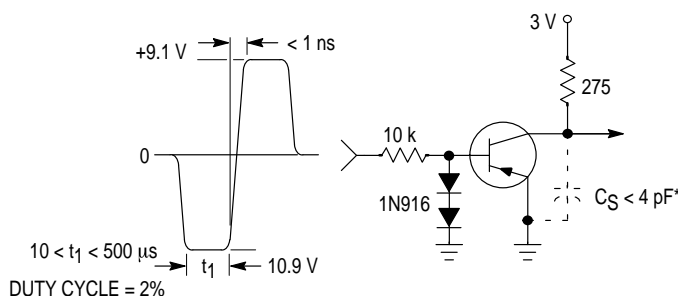
## SWITCHING CHARACTERISTICS

Delay Time	(V <sub>CC</sub> = -3.0 V <sub>dc</sub> , V <sub>BE</sub> = 0.5 V <sub>dc</sub> , I <sub>C</sub> = -10 mA <sub>dc</sub> , I <sub>B1</sub> = -1.0 mA <sub>dc</sub> )	t <sub>d</sub>	—	35	ns
Rise Time		t <sub>r</sub>	—	35	
Storage Time	(V <sub>CC</sub> = -3.0 V <sub>dc</sub> , I <sub>C</sub> = -10 mA <sub>dc</sub> , I <sub>B1</sub> = I <sub>B2</sub> = -1.0 mA <sub>dc</sub> )	t <sub>s</sub>	—	225	ns
Fall Time		t <sub>f</sub>	—	75	

3. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.



**Figure 1. Delay and Rise Time  
Equivalent Test Circuit**



**Figure 2. Storage and Fall Time  
Equivalent Test Circuit**

\* Total shunt capacitance of test jig and connectors

## TYPICAL TRANSIENT CHARACTERISTICS

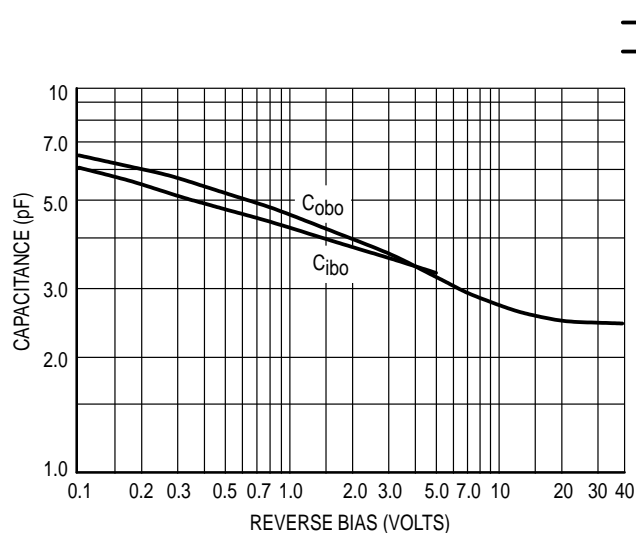


Figure 3. Capacitance

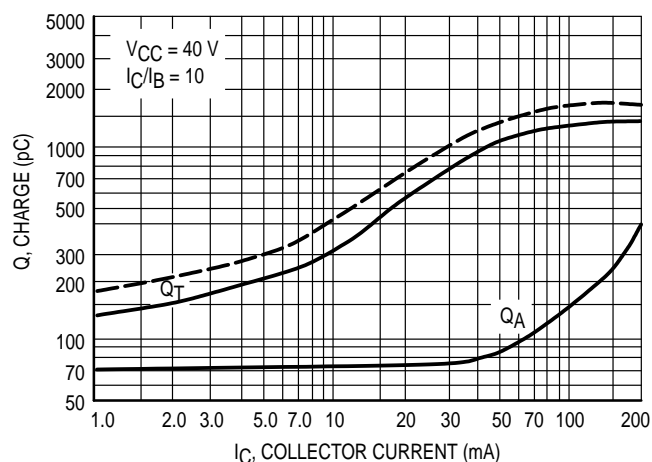


Figure 4. Charge Data

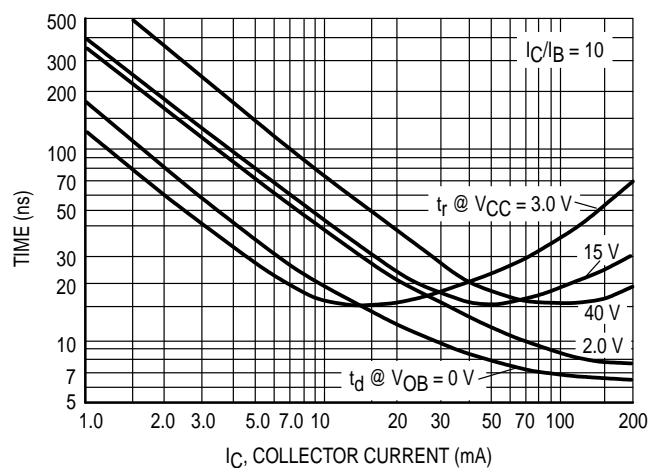


Figure 5. Turn-On Time

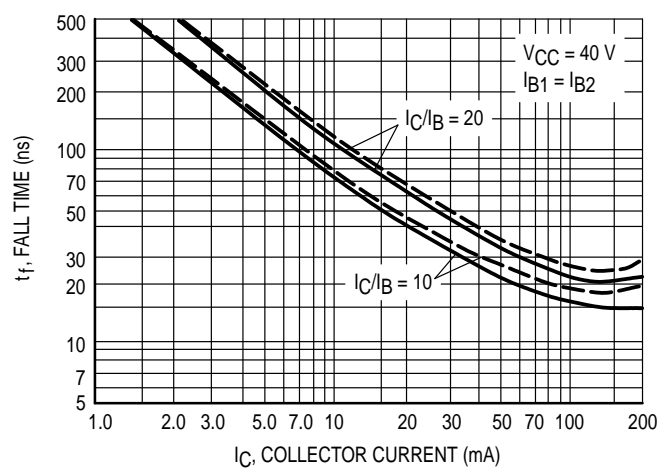


Figure 6. Fall Time

# TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

( $V_{CE} = -5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

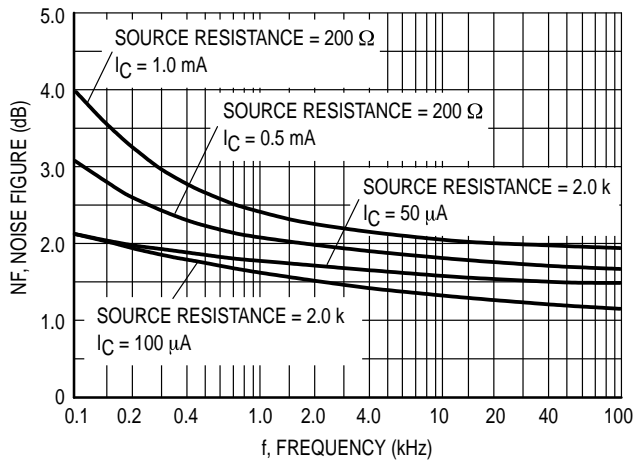


Figure 7.

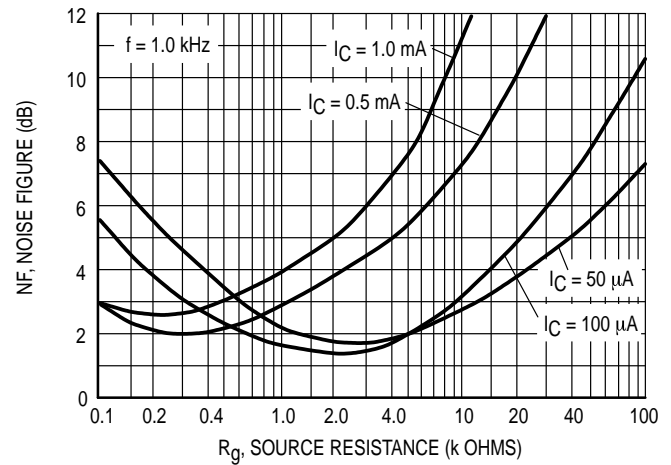


Figure 8.

## h PARAMETERS

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

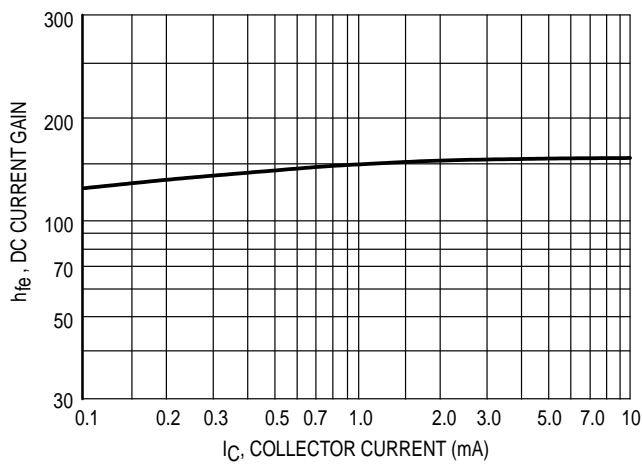


Figure 9. Current Gain

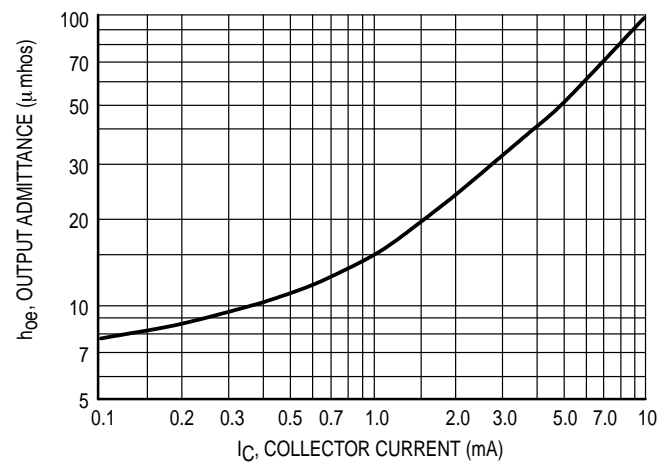


Figure 10. Output Admittance

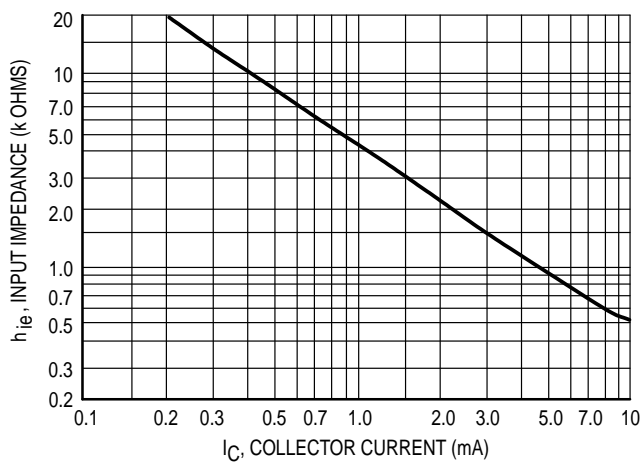


Figure 11. Input Impedance

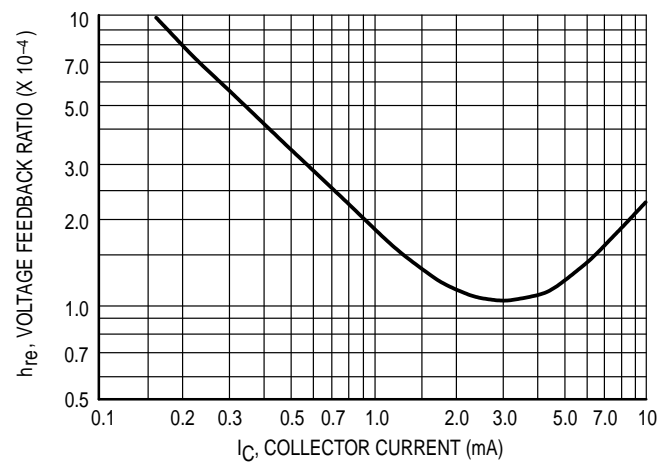


Figure 12. Voltage Feedback Ratio

## TYPICAL STATIC CHARACTERISTICS

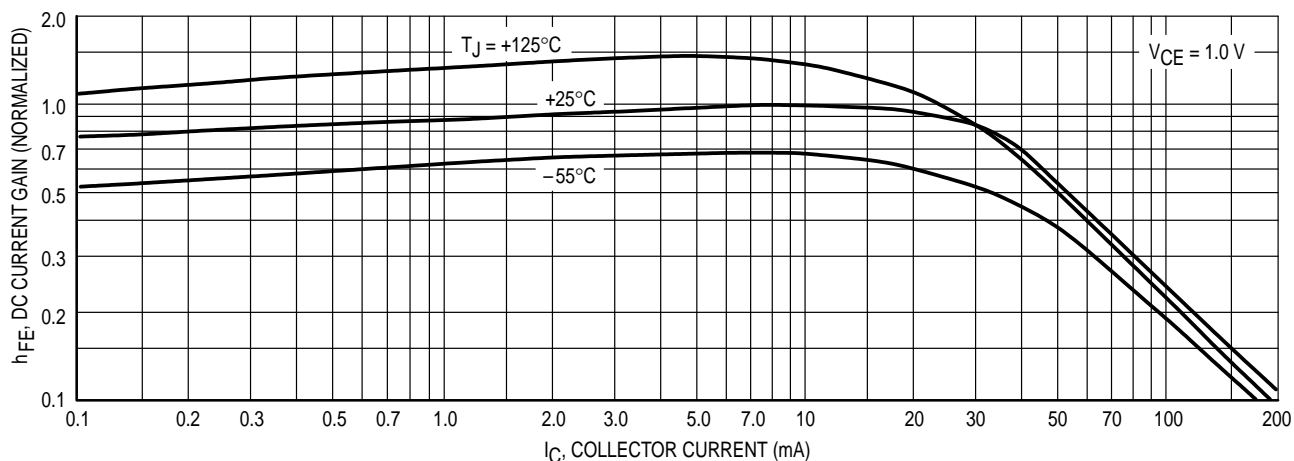


Figure 13. DC Current Gain

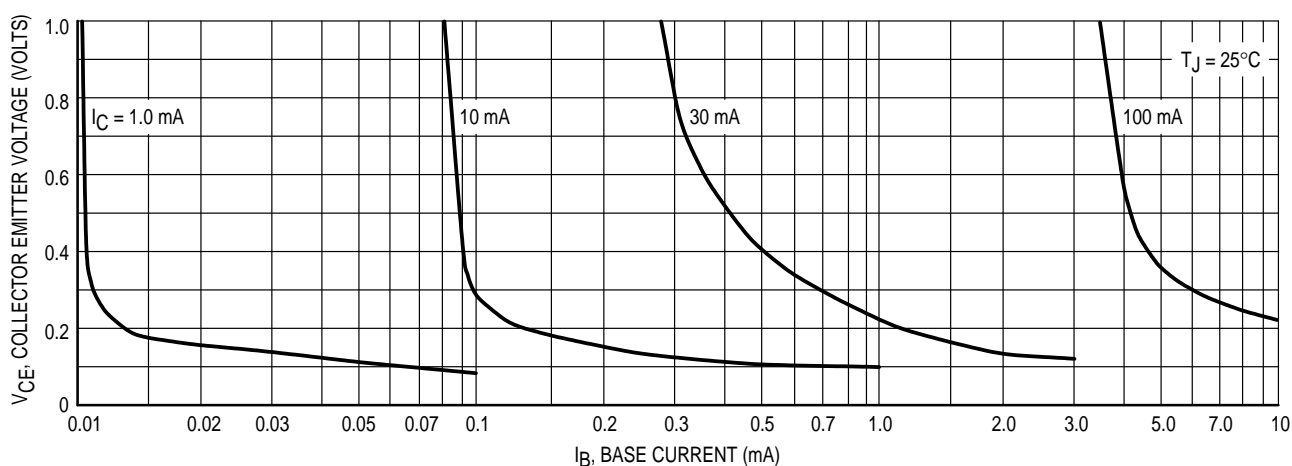


Figure 14. Collector Saturation Region

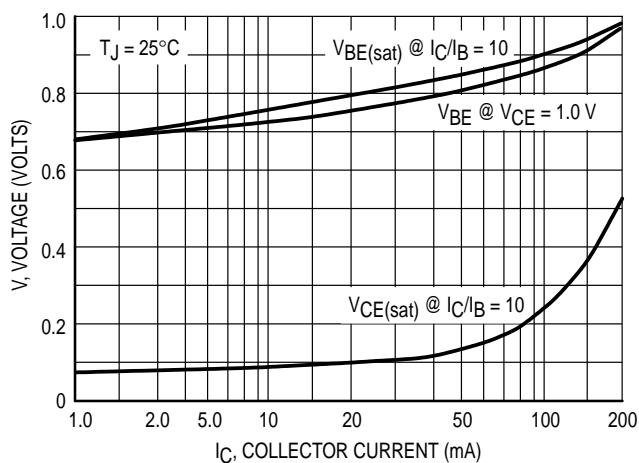


Figure 15. "ON" Voltages

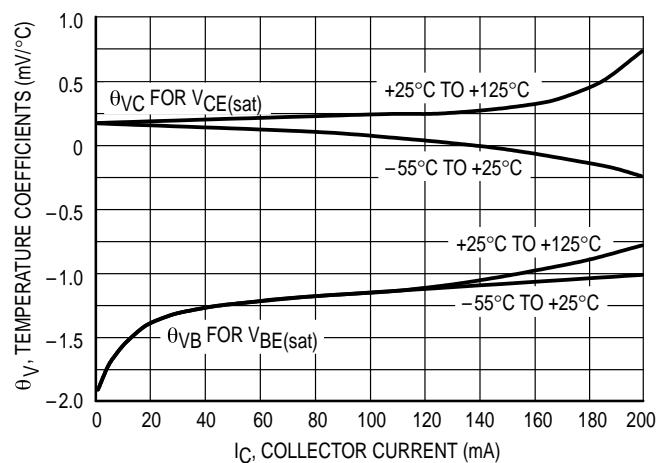


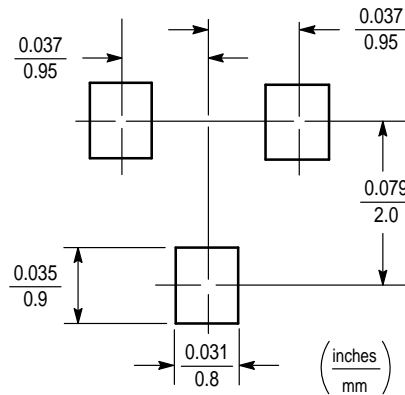
Figure 16. Temperature Coefficients

## INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



**SOT-23**

### SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

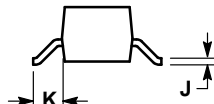
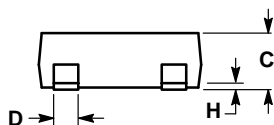
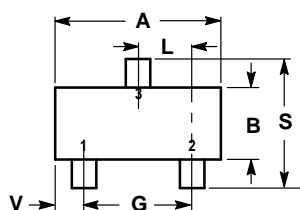
### SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

## PACKAGE DIMENSIONS



## NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

## STYLE 6:

- PIN 1. BASE
- EMITTER
- COLLECTOR

**CASE 318-08**  
**SOT-23 (TO-236AB)**  
**ISSUE AE**

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**USA/EUROPE:** Motorola Literature Distribution;  
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

**JAPAN:** Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki,  
6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

**MFAX:** RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609  
**INTERNET:** <http://Design-NET.com>

**HONG KONG:** Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,  
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

